Silicon PNP Power Transistors

 \dots designed for medium—speed switching and amplifier applications. These devices feature:

- Total Switching Time @ 3.0 A \approx 1.0 μ s (typ)
- hFE (min) = 50 @ 1.0 A
- Low $V_{CE(sat)} = 0.5 \text{ V (typ)} @ I_{C} = 5.0 \text{ A}, I_{B} = 0.5 \text{ A}$
- Excellent Safe Area Limits
- Complementary NPN available 2N3716

2N3791 2N3792

10 AMPERE
POWER TRANSISTORS
PNP SILICON
60-80 VOLTS
150 WATTS



MAXIMUM RATINGS

Rating	Symbol	2N3791	2N3792	Unit
Collector–Base Voltage	V _{CB}	60	80	Volts
Collector–Emitter Voltage	VCEO	60	80	Volts
Emitter–Base Voltage	V _{EB}	7.0	7.0	Volts
Collector Current (Continuous)	IC	10	10	Amps
Base Current (Continuous)	IB	4.0	4.0	Amps
Power Dissipation	PD	150	150	Watts
Thermal Resistance	θJC	1.17	1.17	°C/W
Junction Operating and Storage Temperature Range	T _J , T _{Stg}	−65 to	°C	

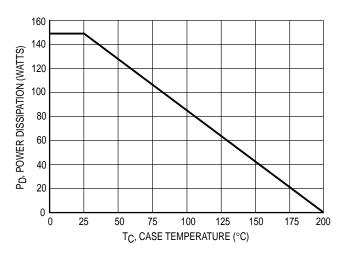


Figure 1. Power-Temperature Derating Curve

Safe Area Limits are indicated by Figures 15, 16. Both limits are applicable and must be observed.

REV 7



ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
Collector–Emitter Sustaining Voltage (1) (I _C = 200 mAdc, I _B = 0)	2N3791 2N3792	VCEO(sus)	60 80	_ _	Vdc
Collector–Emitter Cutoff Current (V _{CE} = 60 Vdc, V _{BE} = -1.5 Vdc) (V _{CE} = 80 Vdc, V _{BE} = -1.5 Vdc) (V _{CE} = 60 Vdc, V _{BE} = -1.5 Vdc, T _C = 150°C) (V _{CE} = 80 Vdc, V _{BE} = -1.5 Vdc, T _C = 150°C)	2N3791 2N3792 2N3791 2N3792	ICEX		1.0 1.0 5.0 5.0	mAdc
Emitter–Base Cutoff Current (VEB = 7.0 Vdc)	All Types	I _{EBO}	_	5.0	mAdc
DC Current Gain (1) (I _C = 1.0 Adc, V _{CE} = 2.0 Vdc) (I _C = 3.0 Adc, V _{CE} = 2.0 Vdc)		hFE	50 30	180 —	_
Collector–Emitter Saturation Voltage (1) (I _C = 5.0 Adc, I _B = 0.5 Adc)		VCE(sat)	_	1.0	Vdc
Base–Emitter On Voltage (1) (I _C = 5.0 A, V _{CE} = 2.0 Vdc) (I _C = 10 Adc, V _{CE} = 4.0 Vdc)		V _{BE} (on)		1.8 4.0	Vdc
Current–Gain — Bandwidth Product (VCE = 10 Vdc, I _C = 0.5 Adc, f = 1.0 MHz)		fΤ	4.0	_	MHz

⁽¹⁾ Pulse Test: Pulse Width $\leq 300 \ \mu s$, Duty Cycle $\leq 2.0\%$.

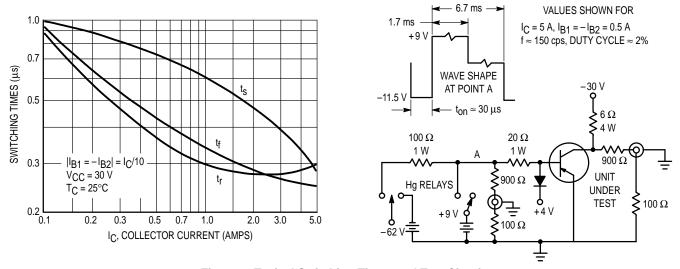


Figure 2. Typical Switching Times and Test Circuit

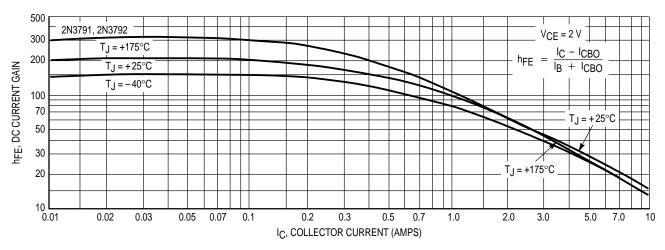


Figure 3. Current Gain Variations

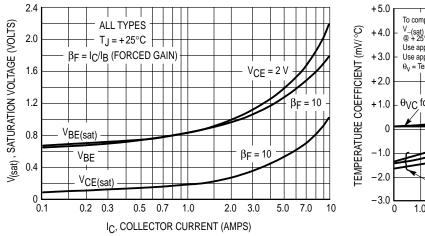


Figure 4. Saturation Voltages

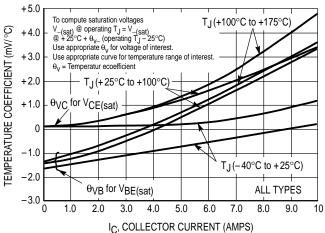


Figure 5. Temperature Coefficients

SAFE OPERATING AREAS

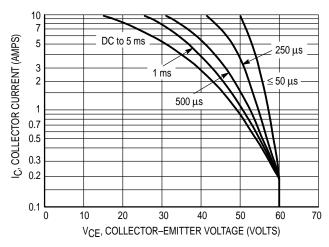


Figure 6. 2N3789, 2N3791

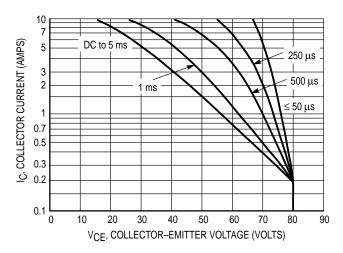


Figure 7. 2N3790, 2N3792

The Safe Operating Area Curves indicate $I_C - V_{CE}$ limits below which the device will not go into secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a collector–emitter

short. (Duty cycle of the excursions make no significant change in these safe areas.) To insure operation below the maximum T_J, the power–temperature derating curve must be observed for both steady state and pulse power conditions.

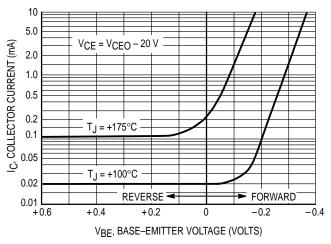
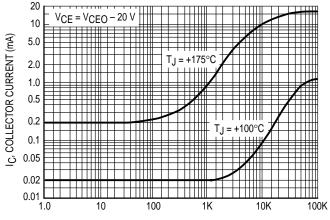


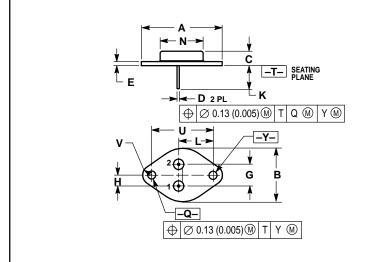
Figure 8. Cut-Off Region Transconductance



RBF, EXTERNAL BASE-EMITTER RESISTANCE (OHMS)

Figure 9. Collector Cut-Off Current versus Base-Emitter Resistance

PACKAGE DIMENSIONS



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	1.550 REF		39.37 REF		
В	-	1.050		26.67	
С	0.250	0.335	6.35	8.51	
D	0.038	0.043	0.97	1.09	
E	0.055	0.070	1.40	1.77	
G	0.430 BSC		10.92 BSC		
Н	0.215 BSC		5.46 BSC		
K	0.440	0.480	11.18	12.19	
L	0.665 BSC		16.89 BSC		
N		0.830		21.08	
Q	0.151	0.165	3.84	4.19	
U	1.187 BSC		30.15 BSC		
٧	0.131	0.188	3.33	4.77	

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR

CASE 1-07 TO-204AA (TO-3) ISSUE Z

2N3791 2N3792

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